

CP212-CZTA44HC NPN - High Voltage Transistor Die

The CP212-CZTA44HC die is a silicon NPN transistor designed for high voltage and high current applications.

		D 1 D 1		80 x 99 MILS	
0		Die Size		00 X 99 WILS	
		Die Thicknes	s	12.5 MILS	
		Base Bondin	ig Pad Size	32 x 12 MILS	
		Emitter Bond	ling Pad Size	48 x 13 MILS	
B	⊏	Top Side Me	etalization	AI – 30,000Å	
		Back Side M	etalization	Cr/Ni/Ag – 1,000Å/5,000	Å/10,000Å
		Scribe Alley	Width	3.5 mils	
		Wafer Diame	eter	4 INCHES	
BACKS	DE COLLECTOR R1	Gross Die Pe	er Wafer	1,380	
Collector-Bas	ATINGS: (T _A =25°C) se Voltage		SYMBOL V _{CBO}	450	
Collector-Emitter Voltage			VCEO	400	V
Emitter-Base Voltage			V _{EBO}	7.0	v
Continuous Collector Current			IC IC	2.0	Å
Peak Collector Current		ICM	3.0	A	
Peak Collect	Operating and Storage Junction Temperature		'CM	5.0	~
		nnerature	TI TII	-65 to +150	°C
Operating an	d Storage Junction Ter		T _{J,} T _{stg}	-65 to +150	°C
Operating an	d Storage Junction Ter	3: (T _A =25°C)	unless otherwise	e noted)	
Operating an ELECTRICA SYMBOL	d Storage Junction Ter	3: (T _A =25°C)	, G		
Operating an ELECTRICA SYMBOL ^I CBO	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS	3: (T _A =25°C)	unless otherwise	e noted) MAX	UNITS
Operating an ELECTRICA SYMBOL ^I CBO ^I EBO	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V _{CB} =400V	3: (T _A =25°C)	unless otherwise	e noted) MAX 500	UNIT: nA
Operating an ELECTRICA SYMBOL ^I CBO ^I EBO ^{BV} CBO	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V _{CB} =400V V _{EB} =5.0V	3: (T _A =25°C)	unless otherwise MIN	e noted) MAX 500	UNITS nA nA
Operating an ELECTRICA SYMBOL ICBO IEBO BVCBO BVCEO	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA	3: (T _A =25°C)	unless otherwise MIN 450	e noted) MAX 500	UNITS nA nA V
Operating an ELECTRICA SYMBOL ICBO IEBO BVCBO BVCEO BVCEO BVEBO	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V _{CB} =400V V _{EB} =5.0V I _C =50µA	5: (T _A =25°C ₪	unless otherwise MIN 450 400	e noted) MAX 500	UNITS nA nA V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT)	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{E} =50 μ A	5: (T _A =25°C ₪	unless otherwise MIN 450 400	e noted) MAX 500 500	UNITS nA nA V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCBO BVEBO VCE(SAT) VCE(SAT)	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{E} =50 μ A I_{C} =500mA, I_{B} =50mA	5: (T _A =25°C ₪	unless otherwise MIN 450 400	e noted) MAX 500 500	UNITS nA NA V V V V
Operating an ELECTRICA SYMBOL ICBO IEBO BVCBO BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT)	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =50 μ A I_{C} =500mA, I_{B} =50mA I_{C} =1.0A, I_{B} =100mA	5: (T _A =25°C ₪	unless otherwise MIN 450 400	e noted) MAX 500 500 0.25 0.50	UNITS nA nA V V V V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT) VCE(SAT)	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{E} =50 μ A I_{C} =500mA, I_{B} =50mA I_{C} =1.0A, I_{B} =100mA I_{C} =2.0A, I_{B} =200mA	5: (T _A =25°C v	unless otherwise MIN 450 400	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT) VBE(SAT) hFE	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{C} =500mA, I_{B} =50mA I_{C} =2.0A, I_{B} =100mA I_{C} =1.0A, I_{B} =1.0mA	5: (T _A =25°C)	450 400 7.0	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVCEO BVCEO VCE(SAT) VCE(SAT) VCE(SAT) VBE(SAT) hFE hFE	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{E} =50 μ A I_{C} =500mA, I_{B} =50mA I_{C} =1.0A, I_{B} =100mA I_{C} =1.0A, I_{B} =1.0mA V_{CE} =10V, I_{C} =10mA	5: (T _A =25°C)	unless otherwise MIN 450 400 7.0 35	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT) VCE(SAT) NBE(SAT) hFE hFE hFE	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =50 μ A I_{C} =500mA, I_{B} =50mA I_{C} =1.0A, I_{B} =100mA I_{C} =1.0A, I_{B} =200mA I_{C} =1.0A, I_{B} =1.0mA V_{CE} =10V, I_{C} =10mA V_{CE} =10V, I_{C} =500mA	5: (T _A =25°C)	unless otherwise MIN 450 400 7.0 35 35	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V
Operating an ELECTRICA SYMBOL ICBO ICBO BVCBO BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT) VCE(SAT) hFE hFE hFE hFE	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{C} =500mA, I_{B} =50mA I_{C} =1.0A, I_{B} =100mA I_{C} =1.0A, I_{B} =1.0mA V_{CE} =10V, I_{C} =10mA V_{CE} =10V, I_{C} =1.0A V_{CE} =10V, I_{C} =1.0A V_{CE} =10V, I_{C} =2.0A	S: (T _A =25°C v	450 400 7.0 35 35 30	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V
Operating an	d Storage Junction Ter L CHARACTERISTICS TEST CONDITIONS V_{CB} =400V V_{EB} =5.0V I_{C} =50 μ A I_{C} =1.0mA I_{C} =500mA, I_{B} =50mA I_{C} =2.0A, I_{B} =100mA I_{C} =1.0A, I_{B} =1.0mA V_{CE} =10V, I_{C} =10mA V_{CE} =10V, I_{C} =500mA V_{CE} =10V, I_{C} =1.0A	5: (T _A =25°C) A A	450 400 7.0 35 35 30 15	e noted) MAX 500 500 0.25 0.50 1.5	UNITS nA NA V V V V V V V V

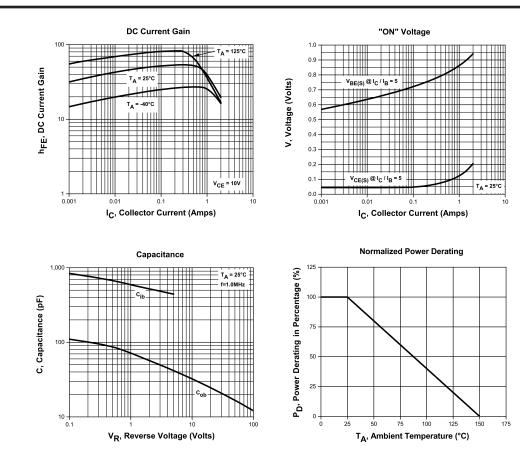
MECHANICAL SPECIFICATIONS:

R0 (8-April 2016)

CP212-CZTA44HC Typical Electrical Characteristics



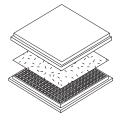
www.centralsemi.com



R0 (8-April 2016)

BARE DIE PACKING OPTIONS



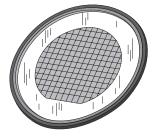


BARE DIE IN TRAY (WAFFLE) PACK

- CT: Singulated die in tray (waffle) pack. (example: CP211-PART NUMBER-CT)
- CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes). (example: CP211-<u>PART NUMBER</u>-CM)

UNSAWN WAFER

WN: Full wafer, unsawn, 100% tested with reject die inked. (example: CP211-PART NUMBER-WN)



SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring, 100% tested with reject die inked. (example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



Visit the Central website for a complete listing of specifications: www.centralsemi.com/bdspecs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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Worldwide Distributors: www.centralsemi.com/wwdistributors

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Product End of Life Notification

PDN ID:	PDN01242
Notification Date:	8/11/22
Last Buy Date:	
Last Shipment Date	8/11/23

Summary: The following bare die transistor devices are discontinued and now classified as of End of Life (EOL).

Although Central Semiconductor Corp. makes every effort to continue to produce devices that have been proclaimed EOL (End of Life) by other manufacturers, it is an accepted industry practice to discontinue certain devices when customer demand falls below a minimum level of sustainability. Accordingly, the following product(s) have been transitioned to End of Life status as part of Central's ongoing Product Portfolio Management. Any replacement products are noted below. The effective date for placing last purchase orders will be six (6) months from the date of this notice and twelve (12) months from the notice date for final shipments, and minimum order quantities may apply. The last purchase and shipment dates may be extended if inventory is available.

* All Plating types (PBFREE,TIN/LEAD) for each item listed are included in this notice.

Central Part Number	Suggested Replacement
CPP55-BC177-CT	N/A
CP188-BC546B-CM	CP388X-BC546B-CT
CP212-CZTA44HC-CT	N/A
CP235-2N3055-CT	N/A
CP235-2N3715-CT	N/A
CP588-BC556B-CM	CP788X-BC556B-CT
CP608-H2N3741-CM	N/A
CP608-TIP32C-CM	N/A
CP608-TIP32C-CT	N/A
CP608-TIP32C-WN	N/A
CP608-2N3741-CT	N/A
CP608-2N6475-CT	N/A
CP611-TIP42-CT	N/A
CP611-TIP42C-CT	N/A
CP611-TIP42C-WN	N/A
CP611-2N5955-CT	N/A
CP611-2N6107-CM	N/A
CP611-2N6107-CT	N/A
CP645-MJE15031-CM	N/A

Central would be happy to assist you by providing additional information or technical data to help locate an alternate source if we have no replacement available. If you would like assistance, please visit https://my.centralsemi.com/submit-inquiry?type=ER to submit an online inquiry.

DISCLAIMER: This End of Life (EOL) notification is in accordance with JEDEC standard JESD48 - Product Discontinuance. Central Semiconductor Corp. will make every effort to offer life-time buy (LTB) opportunities and/or offer replacement devices to existing customers for discontinued devices, however, one or both may not be possible for all devices. Please contact your local Central Semiconductor sales representative for LTB opportunities/additional information.